Trapped ions quantum logic gate with optical tweezers and the Magnus effect

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We consider the implementation of quantum logic gates in trapped ions using tightly focused optical tweezers. Strong polarization gradients near the tweezer focus lead to qubit-state-dependent forces on the ion. We show that these may be used to implement quantum logic gates on pairs of ion qubits in a crystal. The qubit-state-dependent forces generated by this effect are located on the plane perpendicular to the direction of propagation of the laser beams opening alternate ways of coupling to motional modes of an ion crystal. The proposed gate does not require ground-state cooling of the ions although the waist of the tightly focused beam needs to be comparable to its wavelength in order to achieve the needed field curvature. Furthermore, the gate can be implemented on both ground-state and magnetic-field-insensitive clock-state qubits without the need for counterpropagating laser fields. This simplifies the setup and eliminates errors due to phase instabilities between the gate laser beams. Finally, we show that imperfections in the gate execution, in particular, a 30-nm tweezer alignment error, lead to an infidelity of \( \sim 10^{-4} \). In the absence of experimental imperfections and within the limits of the gate model explored in this paper the fidelity is predicted to be \( \sim 0.99988 \) when using a Laguerre-Gaussian beam to suppress photon scattering errors.

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I. INTRODUCTION

Trapped ions are one of the most mature platforms for the implementation of quantum computing, and quantum logic gates have been implemented with very high fidelity in these systems [1,2]. Usually, the quantum logic gates in trapped ions rely on state-dependent forces applied to the ions by laser fields or magnetic fields. The exchange of motional quanta between the ions then leads to effective qubit-qubit interactions. Several recent works have explored how the use of state-of-the-art optical tweezer technology can benefit the trapped ion quantum computer. Optical tweezers can be used to confine atoms very strongly by inducing a dipole in them and find application in neutral atomic quantum simulators, in which tweezers are used to levitate individual atoms [3–7]. In trapped ions, tweezers may be used to tune the sound-wave spectrum in the ion crystal and thereby to program the interactions between the qubits [8–10]. Furthermore, in a recent paper [11] we have proposed combining state-dependent optical tweezers with oscillating electric fields to build a universal trapped ion quantum computer with extremely long ranged interactions between the qubits.

In this paper, we consider another scenario, in which we make use of the strong polarization gradients that occur in optical tweezers. We note that strong gradients in optical potentials have been previously investigated to implement two-qubit gates without the need for ground-state cooling [12–14]. However, our approach utilizes the state-dependent displacement of the tweezer potential due to polarization gradients [15–17]. We propose to use this optical analog of the Magnus effect to implement quantum logic gates in trapped ions [16].

II. SETUP

We consider linearly \( x \)-polarized, Gaussian tweezers, pointing in the \( \sim y \) direction and tightly focused at two qubits, between which we wish to implement a quantum logic gate. The quantum computing platform here considered is a linear crystal of \( N \) alkali-like trapped ions of mass \( m \). In the focal plane the ions experience a strong polarization gradient along the \( x \) direction, such that the polarization is linear (\( \sigma^\pm \)) in the center and circular (\( \sigma^c \)), in the wings of the Gaussian. A direct calculation (see Appendix A) decomposing the field in the focal plane into its circular components (\( \sigma^\pm \)), (and \( \pi \)), shows that, to a good approximation, the circular components are near-Gaussian distributions, displaced in opposite directions along the \( x \) axis. We depict this setup in Fig. 1. Note that the circular components rotate in the \( xy \) plane, i.e., a plane containing the \( \mathbf{k} \) vector of the light. As shown in Fig. 1, the (\( \sigma^c \)), component is displaced by an amount \( \pm \lambda \equiv \pm \lambda/2\pi \), with \( \lambda \) being the tweezer wavelength. As the total field is the superposition of two displaced Gaussians, its intensity is slightly elongated along \( x \). Hollow tweezers (Laguerre-Gaussian) can be used instead of Gaussian ones. This will provide the needed field curvature while keeping near-zero intensity at the center of the beam, drastically reducing the
Hence we may approximate the tweezer potential as tightly focused tweezers. This causes the minima of the tweezer potentials to be shifted depending on the qubit state. (c) Main polarization components for Gaussian and Laguerre-Gaussian \((l = 1, n = 0)\) tightly focused tweezers.

probability of off-resonant scattering that might limit the gate fidelity.

For simplicity, we first consider ions without nuclear spin, such as \(^{40}\text{Ca}^+\), \(^{88}\text{Sr}^+\), \(^{138}\text{Ba}^+\), and \(^{174}\text{Yb}^+\). The qubits are encoded in the electronic ground states of the ion trap, with trap frequency \(\omega_{\text{tr}}\) and projection on the quantization axis. The magnetic field lies along the \(z\) direction, and the tweezers are polarized along the \(x\) direction, such that the ion experiences linearly polarized laser light. The direction along the \(x\) axis is the long direction of the ion trap, with trap frequency \(\omega_{\text{t}}\). The motion of the ions along the \(x\) direction can be described by collective modes of harmonic motion with frequencies \(\omega_{\text{om}}\) and mode vectors \(b_{l,m}\), with \(m\) labeling the mode and \(l\) labeling the ion \([18]\).

We choose the detuning between the tweezers and the D1 transition to be large enough to avoid photon scattering, but much smaller than the spin-orbit coupling splitting of the \(2P\) state. In this way, we can neglect coupling to the \(3P_2\) state. In what follows we will show that this requirement can be satisfied experimentally. Close to the center of the tweezer, strong polarization gradients appear, and as a result, the two qubit states experience slightly different tweezer potentials. In particular, as we show in Fig. 1(a), the optical Magnus effect causes each qubit state to experience a tweezer potential that is offset from the apparent center of the tweezer by \(-k\) \([16]\).

Hence we may approximate the tweezer potential as

\[
\tilde{U}(x) = U_0 \exp \left( -2 \frac{k}{\hat{\sigma}_z} \right) / w_0^2 \quad (1)
\]

\[
\approx -U_0 + \frac{1}{2} \frac{m \omega_{\text{om}}^2}{\omega_{\text{ir}}^2} \hat{\sigma}_z^2 + g x \hat{\sigma}_z \quad (2)
\]

with \(a_{\text{om}} = \sqrt{4U_0(w_0^2 - 4x^2)} / (m \omega_{\text{ir}}^2)\), \(g = 4U_0 \gamma / w_0^2\), and \(U_0 = U_0 \exp(-2k^2 / w_0^2) \approx U_0\). Here, \(U_0\) is the tweezer potential in the center, and the beam waist is \(w_0\). Our approximation replaces the tweezer potential with a harmonic potential and is valid for \(w_0 \gg l_m\), with \(l_m = \sqrt{\hbar / 2m \omega_{\text{tr}}}\). The last term in \(U(x)\) is the result of the spin-dependent force \(g\) coupling the internal state of the qubit, \(\hat{\sigma}_z\), to its motion \(\hat{\sigma}_x\). Thus the optical Magnus effect allows us to straightforwardly implement a quantum gate.

### III. TWEEZER HAMILTONIAN

In the interaction picture with respect to \(\hat{H}_0 = \hbar \omega_{\text{om}} \hat{a}_m \hat{a}_m\), the tweezer Hamiltonian on ions \(i\) and \(j\) is

\[
\hat{H}_1 = A(t) \langle \hat{\sigma}_z^{(i)} \hat{\sigma}_z^{(j)} \rangle. \quad (3)
\]

Here, \(\hat{\sigma}_z^{(i)} = \sum_n b_{i,n} e^{i\omega_{\text{om}} t} (\hat{a}_m^{(i)} \hat{a}_m^{(i)\dagger} + \hat{a}_m^{(i)\dagger} \hat{a}_m^{(i)})\) is the position operator of ion \(i\) in the interaction picture, with \(\hat{a}_m^{(i)}\) being the creation operator for the mode \(m\), and \(0 \leq A(t) \leq 1\) specifies the time dependence of the tweezer intensity. The qubit-state-independent terms in \(\hat{H}_1\) do not alter the dynamics of the quantum gate. We ignore these terms and arrive at

\[
\hat{H}_2 = A(t) \langle \hat{\sigma}_z^{(i)} \hat{\sigma}_z^{(j)} \rangle. \quad (4)
\]

which takes the form of a spin-phonon coupling Hamiltonian reminiscent of the Mølmer-Sørensen scheme for phonon-mediated quantum gates in trapped ions \([19]\). However, at this stage we still have various choices available for \(A(t)\), depending on which type of quantum gate we would like to implement. For instance, pulsed \(A(t)\) could be used to implement fast gates. Here, we choose \(A(t)\) to obtain a geometric phase gate. For this, we set \(\Delta A(t) = -\cos(\varphi + \phi)\), where \(\phi = 0\) assures a smooth ramp of the tweezer intensity and \(\varphi = \omega_{\text{ir}} + \delta\) with the subscript “c” denoting the center-of-mass (c.m.) mode for which \(\omega_{\text{om}} = \omega_{\text{c}}\) and \(b_{l,m} = 1 / \sqrt{N}\). We write the operators \(\hat{x}_i\) and \(\hat{p}_i\) in terms of \(\hat{a}_m\) and \(\hat{a}_m^{\dagger}\) and perform the rotating-wave approximation to arrive at

\[
\hat{H}_3 = \frac{g \ell}{4\sqrt{N}} (\hat{a}_m e^{i\delta t} + \hat{a}_m^{\dagger} e^{-i\delta t}) (\hat{\sigma}_z^{(i)} + \hat{\sigma}_z^{(j)}). \quad (5)
\]

To derive the qubit-qubit interactions forming the geometric phase gate, we perform a unitary transformation \(\hat{U}_1 = e^{-i\hat{a}_m^{\dagger} \hat{a}_m t}\) to eliminate the time dependence, followed by a Lang-Firsov \([20]\) transformation, \(U_2 = \exp(\delta (\hat{a}_m^{\dagger} - \hat{a}_m))\) with \(\delta = \frac{\sqrt{2}}{\hbar} (\hat{\sigma}_z^{(i)} - \hat{\sigma}_z^{(j)})\). Disregarding qubit-independent terms, we obtain

\[
H_{\text{eff}} = \frac{g \ell}{\hbar} \hat{\sigma}_z^{(i)} \hat{\sigma}_z^{(j)}, \quad (6)
\]

with \(\tilde{g} = g \ell / (4\sqrt{N}) = \eta \hat{U}_0\), with the proportionality factor \(\eta = \lambda \ell / (\sqrt{N} w_0^2)\). This Hamiltonian generates qubit-qubit interactions that can be used to implement a geometric phase gate by setting the gate time \(\tau = 2\pi / \delta\) and \(\frac{\Delta \ell}{\hbar} = \pi / 4\).

### IV. CHARACTERIZATION OF THE GATE

We analyze the gate dynamics by performing numerical simulations of the full dynamics generated by the Hamiltonian \(\hat{H}_{\text{sim}} = \hat{H}_0 + \hat{H}_1 + \hat{H}_2\) for a two-dimensional
ion crystal where the tweezer potentials \( \hat{U}(x, j) \) on ions \( i \) and \( j \) have been expanded up to fourth order including spin-independent terms. We use realistic experimental parameters: \( \sim 450 \text{ µW} \) of tweezer laser power focused to a waist of \( w_0 \sim 0.5 \text{ µm} \) and tuned 22 THz to the red from the \( ^2S_{1/2} \rightarrow ^2P_{1/2} \) transition in \(^{174}\text{Yb}^+ \) \( (\lambda = 369.5 \text{ nm}) \). This results in \( \bar{\gamma}/\hbar \sim 1.6 \text{ MHz} \), \( g/\hbar = 2.1 \text{ kHz}/\sqrt{\mathcal{N}} \); setting \( \delta = 2\pi \times 12.2 \text{ kHz}/\sqrt{\mathcal{N}} \), the gate time for the geometric phase gate is \( \tau = 170 \sqrt{\mathcal{N}} \text{ µs} \). With a calculated qubit-state-independent tweezer potential of \( \omega_{\text{tw}} \sim 2\pi \times 37 \text{ kHz} \), the center-of-mass mode frequency \( \omega_{\text{c}}/2\pi \sim 1 \text{ MHz} \) is shifted by \( \sim 2\omega_{\text{tw}}^2/\omega_{\text{r}} \mathcal{N} \sim 2\pi \times 710/\mathcal{N} \text{ Hz} \). This shift can easily be taken into account by correcting \( \delta \) accordingly. In these estimates, we neglected the contribution from other dipole allowed transitions, which are detuned by \( \sim 66 \text{ THz} \) (the relatively weak \( ^2S_{1/2} \rightarrow ^4[3/2]J_{3/2} \) transition) and 115 THz (the strong D2 line) or more.

We consider the gate unitary with a spin-echo sequence given by \( U(0, \tau) = X^{\omega_0}U(\tau/2, \pi)X^{\omega_0}U(0, \tau/2) \), where \( X^{\omega_0} \) is a qubit flip on both qubits. This spin-echo sequence is needed in order to remove local rotations on the qubit states and possible timing errors. We calculate the unitary time evolution operator \( U(0, \tau) \) for a system of two ions with their motional c.m. and stretch modes and truncate their respective Hilbert spaces to \( n_x \leq 18 \) and \( n_z \leq 10 \). In Fig. 2 we show the process fidelity of the gate assuming that the ions are in their motional ground state (\( \bar{n}_s = 0 \)) as a function of gate time.

The gate fidelity of \( F = 0.999989 \) with \( n_x = n_z = 0 \) rivals the current standard approaches. Moreover, the performance of our gate is robust in the presence of thermal occupation of the motional modes. We characterize the gate performance in the presence of thermal phonons using the average gate fidelity [21] (see Appendix C and find that it depends weakly on the motional state of the two ions. In fact, using \( \bar{n}_s = 0.62, \bar{n}_z = 0.23 \), the fidelity is almost unaltered at \( F_\text{th} = 0.999989 \).

In Table I we report the main sources of the gate’s infidelities. One of main experimental challenges is perfect tweezer alignment. We have studied the resilience of the gate in the presence of misalignment of the tweezer in the \( x \) direction, which we denote by \( \epsilon \). In the presence of misalignment, \( \hat{U}_0 \rightarrow U_0 \exp^{-2i(\epsilon + \delta)H \tau/\Delta \tau} \). Thus the misalignment has two effects: (i) It changes the tweezer potential at the center of the tweezer and therefore the phase accumulation in the phase gate, and (ii) it shifts the potential in a qubit-state-dependent way. The second contribution is corrected to lowest order by a spin-echo sequence. Figure 2(b) shows the infidelity as a function of \( \epsilon \). Here we assume that the tweezers are misaligned on both ions in the same way, which seems the experimentally most likely case. The unitary \( U(0, \tau) \) leads to phase-space trajectories for \( \langle x(t) \rangle \) and \( \langle p_x(t) \rangle \) associated with the c.m. motion (see Appendix B). As expected, we find approximately circular phase-space orbits for the even-parity states \( |00\rangle \) and \( |11\rangle \) and very little motion for the odd-parity ones. We see that every state combination leads to ion motion, but the difference in motion still leads to a high fidelity of \( \geq 0.999 \) as shown in Fig. 2(b). For the quoted experimental parameters the fidelity is limited by the scattering rate to 0.99988 when using Laguerre-Gaussian beams. Note, however, that this limit can be further reduced by increasing the detuning at the expense of the required laser power.

### Table I. Main sources of gate errors. We estimate \( \gamma_{\text{th}} \) as the probability of off-resonant scattering in \(^{174}\text{Yb}^+ \) during the gate time (\( \tau = 240 \text{ µs} \)) for Gaussian and Laguerre-Gaussian beams. Other typical sources of error are misalignment \( \epsilon \), tweezer intensity noise \( \Lambda_{1/\tau} \), and timing \( \Delta \tau \). The values here reported are for laser parameters used in our numerical simulations.

<table>
<thead>
<tr>
<th>Error source</th>
<th>( \gamma_{\text{th}} ) (Gaussian)</th>
<th>( \gamma_{\text{th}} ) (Laguerre-Gaussian)</th>
<th>( \epsilon = 30 \text{ nm} )</th>
<th>( \Lambda_{1/\tau} = 0.5% )</th>
<th>( \Delta \tau = \pm 5 \text{ µs} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>( 1 - F )</td>
<td>( 2.4 \times 10^{-3} )</td>
<td>( 1.2 \times 10^{-4} )</td>
<td>( 1.3 \times 10^{-3} )</td>
<td>( 9.3 \times 10^{-5} )</td>
<td>( 2.7 \times 10^{-4} )</td>
</tr>
</tbody>
</table>
V. CLOCK-STATE CASE

While the calculation was performed for the electron spin qubit states in $^{174}$Yb$^+$, it should also be possible to use the hyperfine clock states $|F = m_F = 0\rangle$ and $|F = 1, m_F = 0\rangle$ in $^{171}$Yb$^+$ (Fig. 3). This qubit is insensitive to magnetic field noise, and coherence times of up to an hour have been measured [22]. In this case, the tweezer lasers are formed by a bichromatic copropagating laser field detuned by $\Delta$ from the D1 transition at 369.5 nm with overall detuning $\Delta \ll \omega_{\text{PS}}$, the fine structure splitting. We set the frequency difference in the bichromatic tweezer to 12.6 GHz, corresponding to the transition between the qubit states [23]. The tweezer laser then causes Raman coupling between the qubit states via two distinct paths. In the first path, the qubits are coupled via the state $|1\rangle$ of the tweezer laser, then causes Raman coupling between the qubit states corresponding to the transition between the qubit states [23]. The coupling can be achieved using a pair of Raman beams detuned from the upper state $^3P_{1/2}$ by $\Delta$. In the parentheses are the angular contributions to the various dipole transition elements.

\[ m_F \begin{array}{ccc} -1 & 0 & +1 \end{array} \]

- $^{171}$Yb$^+$
- $\Omega_1^-$
- $\Omega_1^+$
- $\Omega_2^-
- \Omega_2^+$
- $|1\rangle$
- $|0\rangle$
- $\delta$
- $\omega_q$

FIG. 3. Relevant energy levels of $^{171}$Yb$^+$ for implementing the gate on a hyperfine qubit split by $\omega_q$. The coupling can be achieved using a pair of Raman beams detuned from the upper state $^3P_{1/2}$ by $\Delta$. In the parentheses are the angular contributions to the various dipole transition elements.

VI. CONCLUSIONS

In conclusion, we have described a quantum phase gate based on the optical Magnus effect using optical tweezers in a linear chain of trapped ions. The main benefit is that the gate does not require counterpropagating laser fields, greatly simplifying the setup and eliminating errors due to phase instabilities between the gate laser beams. Furthermore, the state-dependent force generated by the Magnus effect allows us to perform the gate operation by coupling to motional modes on the plane perpendicular to the direction of propagation of the tweezers offering further experimental possibilities. The proposed gate does not require ground-state cooling, and can be performed on any pair of ion qubits by spatial addressing. The expected gate fidelity rivals the state of the art also for ions that are not cooled to the ground state of motion.

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APPENDIX A: OPTICAL MAGNUS EFFECT

A key characteristic of a tightly focused beam is the strong field curvature near the focus. This affects not only the local intensity but also its polarization structure. To calculate the polarization structure near the focus, we take a superposition of plane waves labeled by their wave vectors in spherical coordinates, \( \mathbf{k} = (k, \theta, \phi) \). Taking \( k = \omega/c \) as fixed, we write

\[
E(r) \propto \int_{0}^{2\pi} \, d\phi \int_{0}^{\pi} \, d\theta \sin \theta \, u_{i}(\theta, \phi) a(\theta, \phi) e^{i\mathbf{k} \cdot \mathbf{r}}
\]

with \( u_{i}(\theta, \phi) \) being a polarization vector obtained by corotating the \( x \) unit vector when \( \mathbf{k} \) is rotated from \( z \) to \( (\theta, \phi) \), such that \( u_{i}(\theta, \phi) \cdot \mathbf{k} = 0 \); see also Ref. [16]. In the calculation we center the beam around \( \theta = 0 \), and the focal plane is given by \( r = (x, y, 0) \). The shape of the beam is determined by the amplitude function \( a(\theta, \phi) \). For a Gaussian beam we set \( a(\theta, \phi) = \exp(-\theta^{2}/w_{0}^{2}) \); for the lowest-order (\( l = 1 \)) Laguerre-Gaussian (LG) beam we set \( a(\theta, \phi) = \theta \exp(\phi - \theta^{2}/w_{0}^{2}) \). After performing the above integral we rotate the results for tweezers propagating along the \( -y \) direction. Finally, the circular field components \( \sigma^{\pm} \) shown in Fig. 1 of the main text are obtained as the projection onto unit vectors \( (x \pm iy)/\sqrt{2} \). In Fig. 4, all three polarization components for a Laguerre-Gaussian beam are shown. Note that the \( \sigma^{-} \) and \( \sigma^{+} \) components have similar intensity while the \( \pi \) polarization is suppressed by a factor of \( \sim 100 \).

APPENDIX B: PHASE-SPACE DYNAMICS

We study the phase-space dynamics of the ions by simulating the time-dependent Hamiltonian using Trotterization with time steps of \( 10^{-4} \tau \). At each time step we evaluate the expectation value of the \( \langle \hat{x} \rangle \) and \( \langle \hat{p} \rangle \) for the center-of-mass mode. As expected, we find approximately circular phase-space orbits for the even-parity states \( |00 \rangle \) and \( |11 \rangle \) and very little motion for the odd-parity ones. In Fig. 5 it is possible to see the evolution in phase space for all four spin states in the case of perfectly aligned and slightly misaligned tweezers. As described in the main text we simulate numerically the full Hamiltonian defined as \( H_{\text{sim}} = \hat{H}_{0} + \hat{U}(x_{i}) + \hat{U}(x_{f}) \), where in case of misalignment \( \epsilon \), \( \hat{U}(x) \) reads as

\[
U(x) \approx -U_{0} e^{-2(\hat{\lambda}\hat{\xi})+\theta_{x}l^{2}/w_{0}^{2}}
\]

\[
-\hat{U}_{0} + 4\hat{U}_{0}\hat{\sigma}_{x} \hat{\lambda} - \hat{\xi}
\]

\[
+ \frac{1}{2} \hat{U}_{0} \left( \frac{4(w_{0}^{2} - 4\hat{\lambda}^{2})}{w_{0}^{6}} \right) \hat{x}^{2} - \frac{1}{2} \hat{U}_{0} \left( \frac{16(\hat{\lambda}^{2} - 2\hat{\xi} \hat{\lambda})}{w_{0}^{6}} \right) \hat{x}^{2}
\]

\[
- \left( \frac{8\hat{U}_{0}\hat{\sigma}_{x} \hat{\lambda}}{3w_{0}^{3}} - \frac{4(3\hat{\xi}^{2} + \hat{\lambda}^{2})}{3w_{0}^{3}} \right) \hat{\xi}^{3}
\]

\[
+ \left( \frac{8\hat{U}_{0}\hat{\sigma}_{x} \hat{\lambda}}{3w_{0}^{3}} - \frac{4\hat{\xi}^{3} + 3\hat{\lambda}^{2}}{3w_{0}^{3}} \right) \hat{\xi}^{3}
\]

\[
- \left( \frac{2\hat{U}_{0}\hat{\sigma}_{x} \hat{\lambda} \hat{\xi}}{3w_{0}^{3}} - \frac{48w_{0}^{2} + 64(\hat{\xi}^{2} + \hat{\lambda}^{2})}{3w_{0}^{3}} \right) \hat{\xi}^{3}
\]

\[
+ \left( \frac{2\hat{U}_{0} \hat{\sigma}_{x} \hat{\lambda}^{2}}{3w_{0}^{3}} - \frac{24w_{0}^{2}(\hat{\xi}^{2} + \hat{\lambda}^{2}) + 16(\hat{\xi}^{4} + 6\hat{\xi}^{2}\hat{\lambda}^{2} + \hat{\lambda}^{4})}{3w_{0}^{3}} \right) \hat{\xi}^{4}
\]

with

\[
\hat{U}_{0} = U_{0} e^{-2(\hat{\lambda}\hat{\xi})+\theta_{x}l^{2}/w_{0}^{2}}.
\]

A small tweezers misalignment \( \epsilon \) gives rise to new spin-dependent terms in the Hamiltonian that shift the trapping potential in a state-dependent way. In Fig. 5 is shown how the dynamics is affected in the case where the tweezers are misaligned by 30 nm.

APPENDIX C: GATE FIDELITY

We characterize the gate by calculating the average process fidelity as follows [21]:

\[
F(\hat{U}_{\text{id}}, \hat{U}_{\text{sim}}) = \sum_{j} \text{tr}[\hat{U}_{\text{id}} \hat{\sigma}_{j} \hat{U}_{\text{sim}} ^{\dagger} \hat{\sigma}_{j}] + d^{2} / d^{2}(d + 1),
\]

where \( \hat{U}_{\text{id}} \) is the unitary of an ideal geometric phase gate and \( \hat{\sigma}_{j} \) projects
the unitary matrix generated by the time evolution of the Hamiltonian used for the simulations $\hat{U}_{\text{sim}}$ on the Fock state $|n\rangle$ and on $d$-dimensional representation Pauli matrices.


